#### **SECTION A**

#### Question 1.

Which of the following is not the property of an equipotential surface?

(a) They do not cross each other.

(b) The work done in carrying a charge from one point to another on an equipotential surface is zero.

(c) For a uniform electric field, they are concentric spheres.

(d) They can be imaginary spheres.

Answer:

(c) For a uniform electric field, they are concentric spheres.

For a uniform electric field, the equipotential surfaces are the plane surfaces and the gap between two consecutive equipotential surfaces will be same.

Question 2.

An electric dipole placed in an electric field of intensity  $2 \times 10^5$  N/C at an angle of  $30^{\circ}$  experiences a torque equal to 4 N-m. The charge on the dipole of dipole length 2 cm is (a) 7  $\mu$ C

(a) 7 µC (b) 8 mC (c) 2 mC (d) 5 mC Answer:

(c) 2 mC

Given, E =2 × 10<sup>5</sup> N/C,  $\theta$  = 30°,  $\tau$  = 4 N-m, 2a = 2 cm =2 × 10<sup>2</sup> m The torque on an electric dipole in uniform electric field,  $\tau$  = q(2a) – E sin $\theta$ 4 = q × 2 × 10<sup>-2</sup> × 2 × 10<sup>5</sup> × sin 30° q = 2 × 10<sup>-3</sup>C = 2 mC

Question 3.

A metallic plate exposed to white light emits electrons. For which of the following colours of light, the stopping potential will be maximum?

(a) Blue(b) Yellow(c) Red(d) VioletAnswer:

(d) Violet

Einstein's photoelectric equation,

 $eV_0 = h(v - v_0) = hc\lambda - \phi 0$ 

Stopping potential,  $V_0 \propto 1\lambda$ 

 $\therefore$  The colour with minimum wavelength, i.e. violet colour has maximum stopping potential.

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Question 4.

When  $\alpha$ -particles are. sent through a thin gold foil, most of them go straight through the foil, because

(a) a-particles are positively charged

(b) the mass of an  $\alpha$ -particle is more than the mass of an electron

(c) most of the part of an atom is empty space

(d)  $\alpha$ -particles move with high velocity

Answer:

(c) most of the part of an atom is empty space

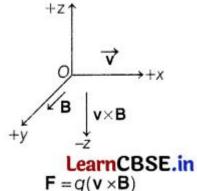
When a-particles are sent through a thin gold foil, most of them go straight without deviation, because most of the part of an atom is empty space.

Question 5.

An electron is moving along positive x-axis in a magnetic field which is parallel to the positive Yaxis. In what direction, will the magnetic force be acting on the electron?

(a) Along – X-axis
(b) Along – Z-axis
(c) Along + Z-axis
(d) Along – Y-axis
Answer:
(c) Along + Z-axis

The force on a moving charge in uniform magnetic field,



 $-q(\mathbf{v} \wedge \mathbf{D})$ 

As, electron has negative charge,  $F_e = -e(v \times B)$  $\therefore$  The direction of force on electron is opposite to the direction of  $v \times B$  i.e. in +z-direction.

Question 6.

The relative permeability of a substance X is slightly less than unity and that of substance Y is slightly more than unity, then

(a) X is paramagnetic and Y is ferromagnetic

(b) X is diamagnetic and Y is ferromagnetic

(c) X and Y both are paramagnetic

(d) X is diamagnetic and Y is paramagnetic Answer:

(d) X is diamagnetic and Y is paramagnetic

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The relative permeability of a substance,  $\mu_r = 1 + \chi$ For diamagnetic substance,  $\chi = -ve$  $\mu_r < 1$ For paramagnetic substance,  $\chi = +ve$  $\mu_r > 1$ Hence, X is diamagnetic and Y is paramagnetic substance.

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Question 7.

An ammeter of resistance 0.81  $\Omega$  reads up to 1 A. The value of the required shunt to increase the range to 10 A is

(a) 0.9 Ω
(b) 0.09 Ω
(c) 0.03 Ω
(d) 0.3 Ω
Answer:
(b) 0.09 Ω

For an ammeter,

 $I = 10 A,G = 0.81 \Omega, I_{a} = 1A$  $:: V_{G} = V_{S} \Rightarrow I_{g} . G = (I - I_{g}).S$  $\therefore$  S = (110–1) × 0.81 = 0.090 Question 8. An electron with angular momentum L moving around the nucleus has a magnetic moment given by (a) e L/2m (b) e L/3m (c) e L/4m (d) e L/mAnswer: (a) e L/2m The magnetic moment of electron moving around nucleus,  $\mu = iA = eT \cdot \pi r^2 = (e_{2\pi rv}) \cdot \pi r^2$  $\therefore \mu = evr2$ As, angular momentum of electron, L = mvr  $\Rightarrow$  vr = Lm From Eqs. (i) and (ii), we get

 $\therefore \mu = eL2m$ Question 9.

The large scale transmission of electrical energy over long distances is done with the use of

transformers. The voltage output of the generators is stepped-up because of (a) reduction of current (b) reduction of current and voltage both (c) power loss is cut down (d) (a) and (c) both Answer: (d) (a) and (c) both

As power, P =V.I = constant For a step-up transformer,  $V_{output} < V_{input} \Rightarrow I_{input} > I_{output}$ Current is reduced and power loss is cut down.

Question 10. The diagram below shows the electric field (E) and magnetic field (B) at a certain time and location.



The direction of the propagation of the electromagnetic wave is

(a) perpendicular to E and B and out of plane of the paper

(b) perpendicular to E and B and into the plane of the paper

(c) parallel and in the same direction as E

(d) parallel and in the same direction as B

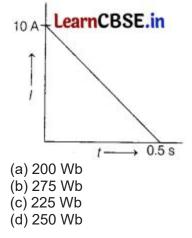
Answer:

(a) perpendicular to E and B and out of plane of the paper

As, the direction of propagation of electromagnetic wave is in the direction of E × B, Flence, the direction of EM wave will be perpendicular to E and B and out of plane of paper.

Question 11.

In a coil of resistance 100  $\Omega$ , a current is induced by changing the magnetic flux through it. The variation of current with time is as shown in the figure. The magnitude of change in flux through coil is



Answer: (d) 250 Wb

Given, R = 100  $\Omega$ According to Faraday's law, I =  $1R\Delta\phi\Delta t$   $\Delta\phi = (I\Delta t) \times R$ The magnitude of change in flux through coil,  $\Delta\phi = (Area \text{ of } I.t \text{ curve}) \times R$ =  $12 \times 0.5 \times 10 \times 100 = 250 \text{ Wb}$ Question 12. The energy of an electron in nth orbit of hydrogen atom is  $E_n = (-13.6/n^2)\text{eV}$ . The negative sign of energy indicates that (a) electron is free to move (b) electron is free to move (c) kinetic energy of electron is equal to potential energy of electron (d) atom is radiating energy Answer:

(b) electron is bound to the nucleus

The energy of electron in nth orbit of FI-atom,

 $E_n = -13.6n_2 \text{ eV}$ 

Here, negative sign indicates that the electron is bound to the nucleus.

For Questions 13 to 16 Two statements are given-one labelled Assertion (A) and other labelled Reason (R). Select the correct answer to these questions from the options as given below.

(a) Both Assertion and Reason are true and Reason is the correct explanation of Assertion.

(b) Both Assertion and Reason are true but Reason is not the correct explanation of Assertion.

(c) Assertion is true but Reason is false.

(d) Both Assertion and Reason are false.

Question 13.

Assertion (A) For the radiation of a frequency greater than the threshold frequency,

photoelectric current is directly proportional to the intensity of the radiation.

Reason (R) Greater the number of energy quanta available, greater is the number of electrons absorbing the energy quanta and greater is number of electrons coming out of the metal. Answer:

(a) Both Assertion and Reason are true and Reason is the correct explanation of Assertion.

For the frequency of radiation,  $v > v_0$  photoelectric effect takes place and the photocurrent is directly proportional to the intensity of radiation.

i.e. Intensity  $\propto$  Photocurrent

Number of photon A·t  ${\color{black} {\bf X}}$  Number of electron t

 $\Rightarrow$  Number of photons oc Number of electrons

Hence, greater the number of photons or quanta, greater is the number of emitted electrons. Question 14.

Assertion (A) Putting p-type semiconductor slab directly in physical contact with n-type semiconductor slab cannot form the p-n junction.

Reason (R) The roughness at contact will be mhch more than inter-atomic crystal spacing and continuous flow of charge carriers is not possible.

Answer:

(a) Both Assertion and Reason are true and Reason is the correct explanation of Assertion.

In p-n junction, there is a continuous flow of charge carriers through the junction. So, by putting p -type semiconductor slab directly in physical contact with n-type semiconductor slab cannot form the p -n junction because of much more at the contact.

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Question 15.

Assertion (A) An electron has a higher potential energy, when it is at a location associated with a negative value of potential and has a lower potential energy when at a location associated with a positive potential.

Reason (R) Electrons move from a region of higher potential to a region of lower potential. Answer:

(c) Assertion is true but Reason is false.

Potential energy of electron at negative potential (-V).

 $U_{-} = (-V)(-e) = eV$ 

Potential energy of electron at positive potential (V),

 $U_{+} = (V)(-e) = -eV$ 

∴ U\_>U₊

As, electrons has negative charge. So, it moves from lower potential region to higher potential region.

Question 16.

Assertion (A) Propagation of light through an optical fibre is due to total internal reflection taking place at the core-cladding interface.

Reason (R) Refractive index of the material of the cladding of the optical fibre is greater than that of the core.

Answer:

(c) Assertion is true but Reason is false.

Propagation of light through an optical fibre is due to total internal reflection at the core-cladding interface. For total internal reflection, the light ray goes from denser medium to rarer medium. Hence, refractive index of material of cladding of optical fibre is less than its core.

#### SECTION B

Question 17.

(i) Name the device which utilises unilateral action of a p-n diode to convert AC into DC.

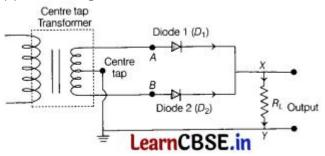
(ii) Draw the circuit diagram of full wave rectifier.

Answer:

(i) Rectifier uses the unilateral action of p-n junction diode to convert AC into DC.

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(ii) Circuit diagram of full wave rectifier



Question 18.

The wavelength  $\lambda$  of a photon and the de Broglie wavelength of an electron of mass m have the same value. Show that the energy of the photon is  $2\lambda m$  c/h times, the kinetic energy of the electron, where c and h have their usual meanings. Answer:

Given, wave length of photon = wave length of electron =  $\lambda$ 

Energy of photon,  $E = \frac{hc}{\lambda}$  ...(i)

Now, de-Broglie wavelength of electron,

$$\lambda = \frac{h}{mv} \Longrightarrow v = \frac{h}{m\lambda}$$

Kinetic energy of electron,

$$K = \frac{1}{2}mv^{2}$$
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$$K = \frac{1}{2}m\left(\frac{h}{m\lambda}\right)^{2} = \frac{h^{2}}{2m\lambda^{2}}$$
 ...(ii)

...

From Eqs. (i) and (ii), we get

$$\frac{E}{K} = \frac{hc}{\lambda} \times \frac{2m\lambda^2}{h^2} = \frac{2mc\lambda}{h}$$
$$E = \left(\frac{2\lambda mc}{h}\right)K$$

...

Question 19.

A ray of monochromatic light passes through an equilateral glass prism in such a way that the angle of incidence is equal to the angle of emergence and each of these angles is 3/4 times the angle of the prism. Determine the angle of deviation and the refractive index of the glass prism. Answer:

Given, angle of incidence (i) = angle of emergence (e) =  $_{34} A = _{34} \times 60^\circ = 45^\circ$ If i = e, then there is condition of  $\delta_m$ .  $\therefore \delta_m = 2i - A = 2 \times 45^\circ - 60^\circ = 30^\circ$ 

: Refractive index of glass prism,

$$n = \frac{\sin\left(\frac{A+\delta_m}{2}\right)}{\sin\left(\frac{A}{2}\right)} = \frac{\sin\left(\frac{60^\circ+30^\circ}{2}\right)}{\sin\left(\frac{60^\circ}{2}\right)}$$
$$= \frac{\sin 45^\circ}{\sin 30^\circ} = \frac{1/\sqrt{2}}{1/2} = \sqrt{2}$$

Question 20.

A heating element using nichrome connected to a 230 V supply draws an initial current of 3.2 A which settles after a few seconds to a steady value of 2.8 A. What is the steady temperature of the heating element, if the room temperature is  $27.0^{\circ}$ C and the temperature coefficient of resistance of nichrome is  $1.70 \times 10^{4^{\circ}}$ C<sup>-1</sup>?

Answer:

Given, V = 230V, I\_0 = 3.2A , I = 2.8A, T\_0 = 27°C  $\alpha = 1.70 \times 10^{4}°C^{-1}$ Using equation R = R<sub>0</sub>(1 +  $\alpha \Delta T$ ) i.e. V/I = (V/I\_0)[1 +  $\alpha \Delta T$ ] and solving,  $\Delta T = T - T_0 = 840$ i.e. T = 840 + 27 = 867°C

Question 21.

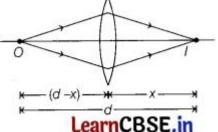
Show that the least possible distance between an object and its real image in a convex lens is 4f, where i is the focal length of the lens.

Or

In an astronomical telescope in normal adjustment, a straight black line of length L is drawn on the objective lens. The eyepiece forms a real image of this line whose length is I. What is the angular magnification of the telescope?

Answer:

Let d be the least distance between object and image for a real image formation.



From lens formula, 1f=1v-1u  $\Rightarrow 1f=1x+1(d-x)=dx(d-x)$   $\Rightarrow x^2 - dx + fd = 0$ For real roots,  $D \ge 0$ i.e.  $d^2 - 4fd \ge 0$   $\because d \ge 4f$ Or

Let  $f_0$  and  $f_e$  be the focal lengths of the objective and eyepiece, respectively. For normal adjustment, the distance from objective to eyepiece is  $f_0 + f_e$ . Taking the line on the objective as object and eyepiece as lens.  $u = -(f_0 + f_e)$  and  $f = f_e$ .  $1v-1[-\{f_0+f_e\}]=1f_e$   $\Rightarrow v = [f_0+t_{et_0}]f_0$ Linear magnification (eyepiece) = vu= Image size Object size  $=f_ef_0=1L$   $\therefore$  Angular magnification of telescope,  $M = f_0f_e=L1$ 

#### SECTION C

Question 22.

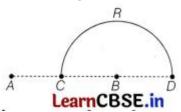
A given coin has a mass of 3.0 g. Calculate the nuclear energy that would be required to separate all the neutrons and protons from each other. For simplicity, assume that the coin is  $\vec{a}$ 

entirely made of 6329Cu atoms (of mass 62.92960 u). (Given,  $m_p = 1.007825$  u and  $m_n = 1.008665$ u). Answer: Number of atoms in 3 g of Cu coin =  $(6.023 \times 10^{23} \times 3) / 63 = 2.86 \times 10^{22}$ Each atom has 29 protons and 34 neutrons. Mass defect, Am =  $[29 m_p + 34m_n - m(6329$ Cu)]c<sup>2</sup> =  $(29 \times 1.007825 + 34 \times 1.008665 - 62.92960)$ uc<sup>2</sup> =  $0.59225 \times 931.5$  MeV Nuclear energy required for 3 g of Cu =  $0.59225 \times 931.5 \times 2.86 \times 1022$  MeV =  $1.58 \times 10^{25}$  MeV

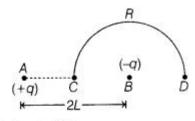
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Question 23.

Charges +q and -q are placed at the points A and B respectively, which are a distance 2L apart. C is the mid-point between A and B. What is the work done in moving a charge +Q along the semi-circle CRD?



Answer:



The potential at point C,

$$V_{\rm C} = \frac{kq}{L} + \frac{k(-q)}{L} = 0$$

The potential at point D, LearnCBSE.in

$$V_D = \frac{kq}{3L} + \frac{k(-q)}{L} = \frac{-2kq}{3L}$$

Work done in moving a charge +Q along CRD,

$$W = Q[V_D - V_C] = Q\left[\frac{-2kq}{3L} - 0\right]$$
$$= -\frac{2Qq}{3L} \times \frac{1}{4\pi\epsilon_0} = -\frac{Qq}{6\pi\epsilon_0 L}$$

Question 24.

The total energy of an electron in the first excited state of the hydrogen atom is about -3.4 eV (i) What is the kinetic energy of the felectron in this state?

(ii) What is the potential energy of the electron in this state?

(iii) Which of the answers above would change, if the choice of the zero of potential energy is changed?

Answer:

Given,  $E_1 = -3.4eV$ 

(i) Kinetic energy,  $K = -E_1 = 3.4eV$ 

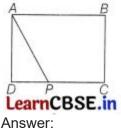
(ii) Potential energy,  $U = -2K = -2 \times 3.4eV = -6.8 eV$ 

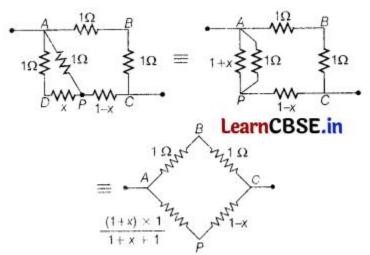
(iii) By changing reference point (zero potential energy) for potential energy, the potential energy will change.

As, E = -U2

So, total energy will also change. There is no any change in kinetic energy. Question 25.

A wire of uniform cross-section and resistance 4  $\Omega$  is bent in the shape of square ABCD. Point A is connected to a point P on DC by a wire AP of resistance 1  $\Omega$ . When a potential difference is applied between A and C, the points B and P are seen to be at the same potential. What is the resistance of the part DP?



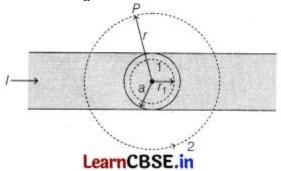


As the points B and P are at the same potential,

11 = (1+x)(2+x)(1+x) $\Rightarrow x = (\sqrt{2-1})\Omega$ 

Question 26.

The given figure shows a long straight wire of a circular cross-section (radius a) carrying steady current I. The current I is uniformly distributed across this cross-section. Calculate the magnetic field in the region r< a and r>a.



Answer:

From given figure in question (i) Consider the case r < a. The amperian loop is a circle labelled 1. For this loop, taking the radius of the circle to be r,  $L = 2\pi r$ Now, the current enclosed ie is not i, but is less than this value. Since, the current distribution is uniform, the current enclosed,  $i_e = i(\pi r_2 \pi a_2) = ir_2 a_2$ Using Ampere's law,  $B(2\pi r) = \mu_0 ir_{2a_2}$  $\mathbf{B} = (\mu_0 i 2\pi a_2)\mathbf{r}$  $\Rightarrow$  B  $\propto$  r (r < a) (ii) Consider the case r > a. The amperian loop, labelled 2, is a circle concentric with the cross-section. For this loop,  $L = 2\pi r$ Using Ampere circuital law, we can write  $B(2\pi r) = \mu_0 i$  $B = \mu_0 i 2\pi r$  $\Rightarrow$  B  $\propto$  1r (r > a) Question 27. Identify the part of the electromagnetic spectrum which

(i) produces heating effect,

(ii) is absorbed by the ozone layer in the atmosphere,

(iii) is used for studying crystal structure.

Write any one method of the production of each of the above radiations.

Answer:

(i) Infrared produces heating effect.

(ii) Ultraviolet ray is absorbed by the ozone layer in the atmosphere.

(iii) X-ray is used to study crystal structure.

Method of the production

(i) Infrared is produced by a non-luminous generator in which an electric current is passed through a coil.

(ii) Ultraviolet ray is produced by mercury-vapour lamp.

(iii) X-ray is produced by acceleration of electron through a certain potential difference.

Question 28.

(i) Define mutual inductance and write its SI unit.

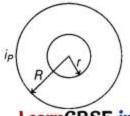
(ii) Two circular loops, one of small radius r and other of large radius R, such that R >> r are placed co-axially with centres coinciding. Obtain the mutual inductance of the arrangement. Or

Two long straight parallel current carrying conductors are kept a distant apart in air. The direction of current in both the conductors is same. Find the magnitude of force per unit length and direction of the force between them. Hence, define one ampere.

Answer:

(i) Mutual induction is defined as the the property of the coil that opposes the change in current in another coil. Its SI unit is henry (H) or  $Tm^2/A$ .





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Let a current i<sub>P</sub> flows through the circular loop of radius R. The magnetic induction at the centre of the loop,

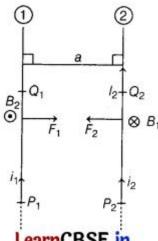
 $B_P = \mu_0 i_p 2R$ 

As r << R, the magnetic induction  $B_P$  may be considered to be constant over the entire crosssectional area of inner loop of radius r. Hence, magnetic flux linked with the smaller loop will be  $\phi_s = B_P A_s = \mu_{0ip} 2R \pi r^2$ 

Also,  $\phi_s = Mi_P$   $M = \phi_{siP} = \mu_0 \pi r_2 2R$ Or

The magnetic induction set-up by the current  $I_1$ , flowing in first conductor at a point somewhere in the middle of second conductor,

 $B_1 = \mu_{0i1} 2\pi a \dots(i)$ 



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The magnetic force acting on the portion  $P_2Q_2$  of length  $I_2$  of second conductor,

 $F_2 = i_2 I_2 B_2 \sin 90^\circ \dots$ (ii)

From Eqs. (i) and (ii), we get

 $\mathsf{F}_2 = \mu_0 i_{112} l_2 2\pi a$ 

 $F_{2l_2} = \mu_{0i_1i_2} 2\pi a \dots (iii)$ 

The magnetic induction  $B_2$  set-up by the current  $I_2$  flowing in second conductor at a point somewhere in the middle of first conductor,

 $B_2 = \mu_{0i2}2\pi a \dots (iv)$ 

The magnetic force acting on the portion  $P_1Q_1$  of length  $I_1$ , of first conductor,

 $F_1 = i_1 I_1 B_2 \sin 90^\circ \dots (v)$ 

From Eqs. (iii) and (v), we get

 $F_1 = \mu_{01112} l_1 2\pi a$  towards second conductor

 $F_{11} = \mu_{011i2} \pi a \dots (vi)$ 

The standard definition of 1 A If  $i_1 = i_2 = 1A$ ,  $l_1 = l_2 = 1m$ and a = 1 m in V/A, then

 $F_{11} = F_{212} = \mu_0 \times 1 \times 12\pi \times 1$ 

= 2 × 10<sup>-7</sup> N/m

: One ampere is that electric current which when flows in each one of the two infinitely long straight parallel conductors placed 1 m apart in vacuum causes each one of them to experience a force of  $2 \times 10^{-7}$  N/m.

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#### SECTION D

Question 29.

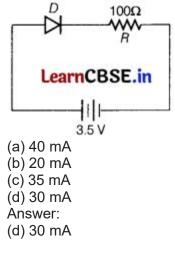
Read the following paragraph and answer the questions that follows.

A semiconductor diode is basically a p-n junction with metallic contacts provided at the ends for the application of an external voltage. It is a two terminal device. When an external voltage is applied across a semiconductor diode, such that p-side is connected to the positive terminal of the battery and n-side to the negative terminal, it is said to be forward biased. Whan an external voltage is applied across the diode, such that n-side is positive and p-side is negative, it is said to be reverse biased.

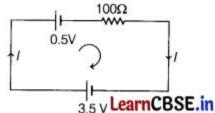
An ideal diode is one whose resistance in forward biasing is zero and the resistance is infinite in

reverse biasing. When the diode is forward biased, it is found that beyond forward voltage called knee voltage, the conductivity is very high. When the biasing voltage is more than the knee voltage, the potential barrier is overcome and the current increases rapidly with increase in forward voltage. When the diode is reverse biased, the reverse bias voltage produces a very small current about a few microamperes which almost remains constant with bias. This small current is reverse saturation current.

(i) In the given figure, a diode D is connected to an external resistance R = 100  $\Omega$  and an emf of 3.5 V If the barrier potential developed across the diode is 0.5 V the current in the circuit will be

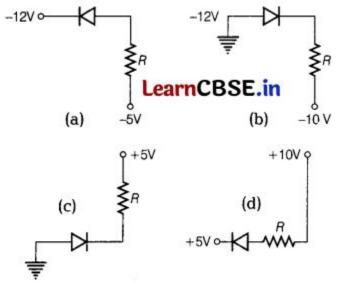


The circuit is represented by

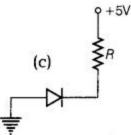


∴ Applying KVL in the loop, 3.5 - 0.5 - 100 | = 0∴ | = 30 mA

(ii) In which of the following figures, the p-n diode is reverse biased?



Answer:



n-side terminal of the diode is connected to negative potential. So, it is reversed biased.

(iii) Based on the V-I characteristics of the diode, we can classify diode as

(a) bilateral device

(b) ohmic device

(c) non-ohmic device

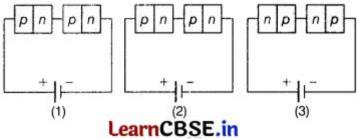
(d) passive element

Answer:

(c) non-ohmic device

Based on V-I characteristics, the diode is classified as non-ohmic device. Or

Two identical p-n junctions can be connected in series by three different methods as shown in the figure. If the potential difference in the junctions is the same, then the correct connections will be

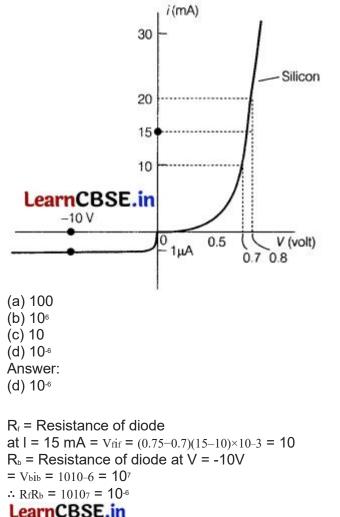


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(a) in the circuits (1) and (2)
(b) in the circuits (2) and (3)
(c) in the circuits (1) and (3)
(d) only in the circuit (1)
Answer:
(b) in the circuits (2) and (3)

For series combination of diode n- side of one diode is connected to p-side of other diode and vice-versa.

(iv) The V-i characteristic of a diode is shown in the figure. The ratio of the resistance of the diode at i = 15 mA to the resistance at V = -10 V is



Question 30. Read the following paragraph and answer the questions that follow.

Types of Lenses and their combination A convex or converging lens is thicker at the centre than at the edges. It converges a beam of

light on refraction through it. It has a real focus. Convex lens is of three types : Double convex lens, Plano-convex lens and Concavo-convex lens.

Concave lens is thinner at the centre than at the edges. It diverges a beam of light on refraction through it. It has a virtual focus. Concave lenses are of three types : Double concave lens. Plano-concave lens and Convexo-concave lens.

When two thin lenses of focal lengths  $f_1$  and  $f_2$  are placed in contact with each other along their common principal axis, then the two lens system is regarded as a single lens of focal length f and

 $1f=1f_1+1f_2$ 

If several thin lenses of focal lengths  $f_1, f_2, \dots, f_n$  are placed in contact, then the effective focal length of the combination is given by

 $1f=1f_1+1f_2+\ldots+1f_n$ 

and, in terms of power, we can write

 $P = P_1 + P_2 + \dots + P_n$ 

The value of focal length and power of a lens must be used with proper sign consideration. (i) Two thin lenses are kept co-axially in contact with each other and the focal length of the combination is 80 cm. If the focal length of one lens is 20 cm, the focal length of the other would be

(a) -26.7 cm (b) 60 cm (c) 80 cm (d) 30 cm Answer: (a) -26.7 cm Given, f = 80 cm,  $f_1 = 20$  cm For combination of lens,

 $1f=1f_1+1f_2$ 

 $18 = 120 + 1f_2$ 

 $f_2 = -26.7$  cm

(ii) A spherical air bubble is embedded in a piece of glass. For a ray of light passing through the bubble, it behaves like a

(a) converging lens

(b) diverging lens

(c) mirror

(d) thin plane sheet of glass

Answer:

(b) diverging lens

A spherical air bubble embedded in a piece of glass behaves as a diverging lens.

(iii) Lens generally used in magnifying glass is
(a) single concave lens
(b) single convex lens
(c) combination of convex lens of lower power and concave lens of lower focal length
(d) plano-concave lens
Answer:
(b) single convex lens

Single convex lens is used in magnifying glass.

(iv) The magnification of an image by a convex lens is positive only when the object is placed
(a) at its focus F
(b) between F and 2F
(c) at 2F
(d) between F and optical centre
Answer:
(d) between F and optical centre

The magnification of an image by convex lens is positive only when the object is placed between focal point (F) and optical centre, because image formed by the convex lens for this location object is virtual and magnified and for real image, m = -ve. For virtual image, m = +ve.

Or

A convex lens of 20 cm focal length forms a real image which is three times magnified. The distance of the object from the lens is

(a) 13.33 cm
(b) 14 cm
(c) 26.66 cm
(d) 25 cm
Answer:
(c) 26.66 cm

Given, f + 20 cm, m = -3 = vu= v = -3uBy lens formula, 1v-1u=1f1-3u-1u=120u = -26.66 cm  $\therefore$  Distance of the object = -26.66 cm LearnCBSE.in

#### SECTION E

Question 31.

(i) Draw a ray diagram for the formation of image of a point object by a thin double convex lens having radii of curvature  $R_1$  and  $R_2$ . Hence, derive lens Maker's formula.

(ii) A converging lens has a focal length of 10 cm in air. It is made of a material of refractive index 1.6. If it is immersed in a liquid of refractive index 1.3, find its new focal length. Or

(i) Define a wavefront. How is it different from a ray?

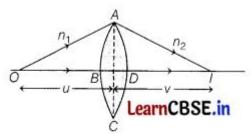
(ii) Using Huygens' construction of secondary wavelets, draw a diagram showing the passage of a plane wavefront from a denser to a rarer medium. Using it verify Snell's law.

(iii) In a double slit experiment, using light of wavelength 600 nm and the angular width of the fringe formed on a distant screen is 0.1°. Find the spacing between the two slits.

(iv) Write two differences between interference pattern and diffraction pattern. Answer:

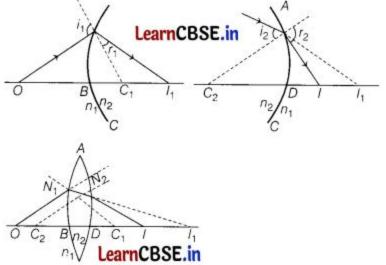
(i) Lens Maker's formula

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When a ray refracts from a lens (double convex), in above figure, then its image formation can be seen in term of two steps:

Step 1 The first refracting surface forms the image  $I_1$ , of the object O.



Step 2 The image of object 0 for first surface acts like a virtual objects for the second surface. Now for the first surface ABC, ray will move from rarer to denser medium, then

 $n_2Bl_1+n_1OB=n_2-n_1BC_1$  .....(i)

Similarly for the second interface ADC, we can write

 $n_1Dl_{n_2}Dl_1 = n_2 - n_1DC_2$  .....(ii)

 $\mathsf{DI}_1$  is negative as distance is measured against the direction of incident light.

Adding Eqs. (i) and (ii), we get

$$\frac{n_2}{Bl_1} + \frac{n_1}{OB} + \frac{n_1}{Dl} - \frac{n_2}{Dl_1} \approx \frac{n_2 - n_1}{BC_1} + \frac{n_2 - n_1}{DC_2}$$

or  $\frac{n_1}{DI} + \frac{n_1}{OB} = (n_2 - n_1) \left(\frac{1}{BC_1} + \frac{1}{DC_2}\right) \dots$ (iii)

LearnCBSE.in (: for thin lens,  $BI_1 = DI_1$ )

Now, if we assume the object to be at infinity, i.e. OB  $\rightarrow \infty$ , then its image will form at focus F (with focal length f).

i.e. DI = f, thus Eq. (iii) can be rewritten as

$$\frac{n_1}{f} + \frac{n_1}{\infty} = (n_2 - n_1) \left( \frac{1}{BC_1} + \frac{1}{DC_2} \right)$$
$$\frac{n_1}{f} = (n_2 - n_1) \left( \frac{1}{BC_1} + \frac{1}{DC_2} \right) \qquad \dots \text{ (iv)}$$

or

Now according to the sign conventions

$$BC_1 = + R_1 \text{ and } DC_2 = - R_2 \qquad \dots \text{ (v)}$$

Substituting Eq. (v) in Eq. (iv), we get

$$\frac{n_1}{f} = (n_2 - n_1) \left( \frac{1}{R_1} - \frac{1}{R_2} \right)$$
$$\frac{1}{f} = \left( \frac{n_2}{n_1} - 1 \right) \left( \frac{1}{R_1} - \frac{1}{R_2} \right)$$
$$\frac{1}{f} = (n_{21} - 1) \left( \frac{1}{R_1} - \frac{1}{R_2} \right)$$

This formula is known as lens Maker's formula.

(ii) Given, for a converging lens,  $f_a = 10 \text{ cm}, u_1 = 1.6, u_m = 1.3$ 

By lens Maker's formula,

$$\frac{1}{f_a} = \left(\frac{\mu_I}{\mu_a} - 1\right) \left(\frac{1}{R_1} - \frac{1}{R_2}\right) \qquad \dots (i)$$

$$\frac{1}{f_m} = \left(\frac{\mu_I}{\mu_m} - 1\right) \left(\frac{1}{R_1} - \frac{1}{R_2}\right) \qquad \dots (ii)$$

From Eqs. (i) and (ii), we get

$$\frac{f_m}{f_a} = \frac{\left(\frac{\mu_I}{\mu_a} - 1\right)}{\left(\frac{\mu_I}{\mu_m} - 1\right)} = \frac{\left(\frac{1.6}{1} - 1\right)}{\left(\frac{1.6}{1.3} - 1\right)}$$
$$f_m = 26 \,\mathrm{cm} \times f_a$$

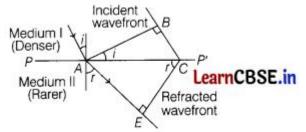
ः Or

(i) A surface on which the wave disturbance is in same phase at all points is called wavefront. A wavefront is different from a ray in following manner

(a) The ray indicates the direction of propagation of • wave, while the wavefront is the surface of constant phase.

(b) The ray at each point of a wavefront is normal to the wavefront at the point.

(ii) Consider AS is incident plane wavefront and CE is refracted wavefront.



where,  $n_1v_1$  = refractive index and speed of light of first medium  $n_2v_2$  = refractive index and speed of light of second medium. From the diagram,

$$\sin i = \frac{BC}{AC} = \frac{v_1 t}{AC} \text{ and } \sin r = \frac{AE}{AC} = \frac{v_2 t}{AC}$$
  
$$\therefore \qquad \frac{\sin i}{\sin r} = \frac{v_1 t}{v_2 t} = \frac{v_1}{v_2} = \frac{n_2}{n_1} = n_{12}$$
  
$$\therefore \qquad \frac{\sin i}{\sin r} = n_{12} \text{ LearnCBSE.in}$$

This is called Snell's law. (iii) Given,  $\lambda = 600 \text{ nm} = 600 \times 10^{-9}\text{m}$ Angular width,  $\theta = 0.1^{\circ} = 0.1 \times \pi 180 \text{ rad}$   $\therefore$  Angular width ( $\theta$ ) is given by  $\theta = \lambda a$  $\therefore a = \lambda \theta = 600 \times 10^{-9} 0.1 \times \pi 180$ 

 $= 3.4 \times 10^{-7}$ 

(iv) Two differences between interference pattern and diffraction pattern are as follow Table 1

Interference

Interference fringes are formed, when the two light rays from the coherent sources are superimposed.

All bright fringes are equally illuminated.

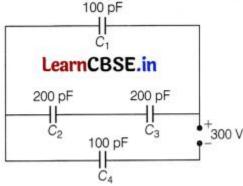
Diffraction

Diffraction fringes are formed due to superposition of light rays from the same source. Central fringe is brightest and all other fringes have intensity in decreasing order.

Question 32.

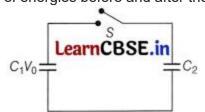
(i) Derive an expression for the capacitance of a parallel plate capacitor with air present between the two plates.

(ii) Obtain the equivalent capacitance of the network shown in figure. For a 300 V supply, determine the charge on each capacitor.



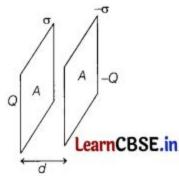
Or

(i) A dielectric slab of thickness t is kept between the plates of a parallel plate capacitor with plate separation d (t < d). Derive the expression for the 'capacitance of the capacitor. (ii) A capacitor of capacity  $C_1$  is charged to the potential of  $V_0$ . On disconnecting with the battery, it is connected with an uncharged capacitor of capacity  $C_2$  as shown in the figure. Find the ratio of energies before and after the connection of switch S.



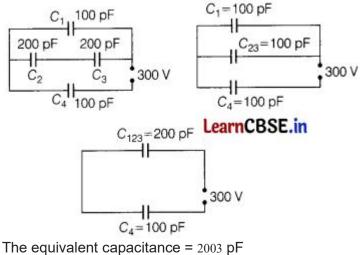
Answer:

(i) Let the two plates be kept parallel to each other separated by a distance d and crosssectional area of each plate is A.



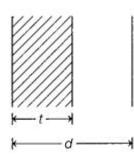
Electric field by a single thin plate,  $E = \sigma/2\epsilon_0$ Total electric field between the plates,  $E = \sigma/2\epsilon_0 = Q/A\epsilon_0$ Potential difference between the plates,  $V = Ed = [Q/A\epsilon_0]d$ Capacitance,  $C = Q/V = A\epsilon_0/d$ 

(ii)



The equivalent capacitance = 2003 pF Charge on  $C_4 = 2003 \times 10^{-12} \times 300 = 2 \times 10^{-8} \text{ C}$ Potential difference across  $C_4$ =  $200 \times 10^{-12} \times 3003 \times 100 \times 10^{-12} = 200\text{V}$ Potential difference across,  $C_1 = 300 - 200 = 100\text{V}$ Charge on  $C_1 = 100 \times 10^{-12} \times 100$ =  $1 \times 10^{-8} \text{ C}$ Potential difference across  $C_2$  and  $C_3$  series combination = 100 VPotential difference across  $C_2$  and  $C_3$  each = 50 VCharge on  $C_2$  and  $C_3$  each =  $200 \times 10^{-12} \times 50$ =  $1 \times 10^{-8} \text{ C}$ Or

(i)



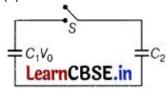
The potential difference between the plates of capacitor, LearnCBSE.in

$$V = V_1 + V_2$$
  
=  $E_1 t + E_2 (d - t)$   
=  $\frac{\sigma t}{K \varepsilon_0} + \frac{\sigma (d - t)}{\varepsilon_0}$   
=  $\frac{\sigma}{\varepsilon_0} \left[ \frac{t}{K} + (d - t) \right]$ 

The capacitance of the capacitor,

$$C = \frac{q}{V} = \frac{\sigma A}{\frac{\sigma}{\varepsilon_0} \left[ \frac{t}{\kappa} - (d - t) \right]}$$
  
$$\therefore \qquad C = \frac{\varepsilon_0 A}{d - t + \frac{t}{\kappa}}$$

(ii)



Before the connection of switch S, initial energy,  $U_i = 12 C_1 v_{0^2} + 12 C_2 v_{0^2} = 12 C_1 v_{0^2}$ After the connection of switch S common potential,

$$V = \frac{C_1 V_1 + C_2 V_2}{C_1 + C_2} = \frac{C_1 V_0}{C_1 + C_2}$$

Final energy, Uf

$$= \frac{1}{2} (C_1 + C_2) \frac{(C_1 V_0)^2}{(C_1 + C_2)^2} = \frac{1}{2} \frac{C_1^2 V_0^2}{(C_1 + C_2)^2}$$

$$U_f: U_i = C_1 / (C_1 + C_2)$$

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Question 33.

(i) Draw graphs showing the variations of inductive reactance and capacitive reactance with frequency of applied AC source.

(ii) Draw the phasor diagram for a series L-C-R circuit connected to an AC source.

(iii) When an alternating voltage of 220V is applied across a device X, a current of 0.25A flows which lags behind the applied voltage in phase by ( $\pi/2$ ) rad. If the same voltage is applied across another device Y, the same current flows but now it is in phase with the applied voltage. (a) Name the devices X and Y.

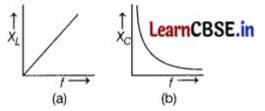
(b) Calculate the current flowing in the circuit, when the same voltage is applied across the series combination of X and Y.

Or

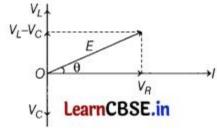
(i) A series L-C-R circuit is connected to an AC source. Using the phasor diagram, derive the expression for the impedance of the circuit.

(ii) Plot a graph to show the variation of current with frequency of the AC source, explaining the nature of its variation for two different resistances  $R_1$  and  $R_2$  ( $R_1 < R_2$ ) at resonance. Answer:

(i) The graphs of inductive reactance  $(X_{\scriptscriptstyle L})$  and capacitive reactance  $(X_{\scriptscriptstyle C})$  with frequency are given below



(ii) The phasor diagram for series L-C-R circuit connected with AC is given below



(iii) (a) In device X, current lags behind the voltage by  $\pi/2$ , X is an inductor. In device X current in phase with the applied voltage, Y is resistor.

(b)  

$$V_0 = 220 \text{ V}, I_1 = 0.25 \text{ A}$$
  
 $\therefore \quad X_L = \frac{V_0}{I_1} = \frac{220}{0.25} = 880 \Omega$   
Also,  $V_0 = 220 \text{ V}, I_2 = 0.25 \text{ A}$   
 $\therefore \quad R = \frac{V_0}{I_2} = \frac{220}{0.25} = 880 \Omega$   
 $\therefore \text{ Current}, I = \frac{V_0}{\sqrt{R^2 + X_L^2}}$   
 $\therefore \quad I = \frac{220}{\sqrt{(880)^2 + (880)^2}} = 0.117 \text{ A}$ 

(i) Vc VR 0000  $V_1 - V_C$ R С 0 VR Vc Έ LearnCBSE.in L-C-R circuit The voltage applied,  $E = E_0 \sin \omega t$ The voltage across L, C and R is given by  $V_L = i X_L, V_C = i X_C$ and  $V_{R} = i R$ From the phasor diagram,  $E^2 = (V_L - V_C)^2 + V_R$  $= i^{2}[R^{2} + (X_{L} - X_{C})^{2}]$  $E = iR_2 + (X_L - X_C)_2 - ---$ The impedance of the circuit is given by  $z = Ei = R_2 + (XL - XC)_2 - \tan \phi = V_L - V_C V_R = X_L - X_C R$ 

(ii) The graph for the variation of current with frequency of AC source is given below Current

